L850F-06-55CU

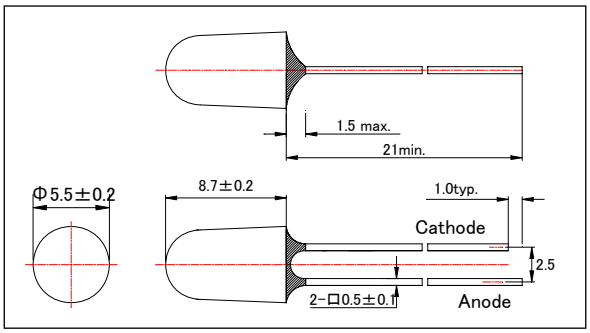
Infrared LED Lamp for High Current Drive

L850F-06-55CU is an AlGaAs LED mounted on a copper made lead frame with a clear epoxy lens. On forward bias it emits a spectral band of radiation, which peaks at 850nm. These devices are intended to be operated at pulsed current of 2A under max. 4.3V.

<Specifications>

1. Product Name: Infrared LED Lamp
2. Type Number: L850F-06-55CU
3. Chip:
   - Chip material: AlGaAs
   - Dimension: 550um x 550um
   - Peak Wavelength: 850nm typ.
4. Package
   - Type: Φ5mm Clear Molding
   - Resin Material: Epoxy Resin
   - Lead Frame: Cu made

Outer Dimension (Unit:mm)



Absolute Maximum Ratings[Ta=25℃]			
Item	Symbol	Maximum Rated Value	Unit
Power Dissipation	PD	150	mW
Forward Current	IF	100	mA
Pulse Forward Current*	IFP	2000	mA
Reverse Voltage	VR	5	V
Junction Temperature	Tj	100	℃
Thermal Resistance**	Rthja	150	K/W
Operating Temperature	TOPR	-30 ~ +85	℃
Storage Temperature	TSTG	-30 ~ +100	℃
Soldering Temperature***	TSOL	265	℃

* Duty=1% and Pulse Width=10us.
** Junction - ambient, leads 7mm, soldered on PCB
*** Soldering condition must be completed within 3 second at 265℃.

Electro-Optical Characteristics [Ta=25℃]						
Item	Symbol	Condition	Minimum	Typical	Maximum	Unit
Forward Voltage	VF VFP	IF=50mA		1.42	1.50	V
		IFP=1A		3.2	3.5	
		IFP=2A		3.6	4.3	
Reverse Current	IR	VR=5V			10	uA
Total Radiated Power*	PO	IF=50mA	18	24		mW
Radiant Intensity**	IE	IF=50mA	90	120		mW/sr
Peak wavelength	λP	IF=50mA	835	850	865	nm
Half Width	Δλ	IF=50mA		40		nm
Viewing Half Angle	θ1/2	IF=50mA		±8		deg
Rise Time	tr	IF=50mA		15		ns
Fall Time	tf	IF=50mA		10		ns

* Measured by Photodyne #500
** Measured by Tektronix J-6512

RoHS Compliant

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